

INCHANGE SEMICONDUCTOR

isc Silicon NPN Power Transistor

BD829

DESCRIPTION

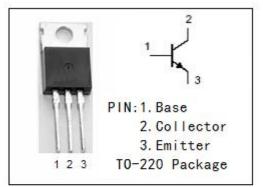
- Collector-Emitter Breakdown Voltage-: V_{(BR)CEO}= 80V(Min)
- High DC Current Gain
- Low Saturation Voltage
- Complement to Type BD828
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

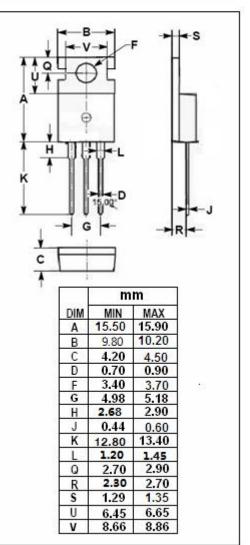
APPLICATIONS

 Designed for driver-stages in hi-fi amplifiers and television circuits.

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)									
SYMBOL	PARAMETER	VALUE		UNIT					
V _{CBO}	Collector-Base Voltage		100	V					
V _{CEO}	Collector-Emitter Voltage	1	80	V					
V _{EBO}	Emitter-Base Voltage	5		V					
lc	Collector Current-Continuous	1.0		А					
I _{CP}	Collector Current-Peak	1.5		A					
Pc	Collector Power Dissipation @ T _a =25°C	2		W					
	Collector Power Dissipation @ $T_c=25^{\circ}C$	10							
TJ	Junction Temperature	150		°C					
T _{stg}	Storage Temperature Range	-65~150		°C					
THERMAL CHARACTERISTICS									
SYMBOL	PARAMETER		MAX	UNIT					
R _{th j-c}	Thermal Resistance, Junction to Case		12.5	°C/W					
R _{th j-a}	Thermal Resistance, Junction to Ambie	62.5	°C/W						

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)







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ELECTRICAL CHARACTERISTICS

$T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
Vceo(sus)	Collector-Emitter Breakdown Voltage	I _C = 30mA; I _B = 0	60			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 500mA; I _B = 50mA			0.5	V
$V_{\text{BE(on)}}$	Base-Emitter On Voltage	I _C = 0.5A ; V _{CE} = 2V			1.0	V
Ісво	Collector Cutoff Current	V _{CB} = 30V; I _E = 0			0.1	uA
		V _{CB} = 30V; I _E = 0; T _C = 125℃			10	
I _{EBO}	Emitter Cutoff Current	V _{EB} = 5V; I _C = 0			10	uA
h _{FE-1}	DC Current Gain	I _C = 5mA ; V _{CE} = 2V	25			
h _{FE-2}	DC Current Gain	I _C = 150mA ; V _{CE} = 2V	40		250	
h _{FE-3}	DC Current Gain	I _C = 500mA ; V _{CE} = 2V	25			
f⊤	Current-Gain—Bandwidth Product	I _C = 50mA ; V _{CE} = 5V		250		MHz

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